

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Attorney Docket No. 040373/0300

Applicant: Toshiyuki HIROTA et al.

Title: SEMICONDUCTOR DEVICE WITH HIGH- AND LOW-DENSITY REGIONS OF TRANSISTOR ELEMENTS ON SINGLE SEMICONDUCTOR SUBSTRATE, AND METHOD OF MANUFACTURING SUCH SEMICONDUCTOR DEVICE

Serial No.: 09/741,195

Filed: December 21, 2000

Examiner: Vu, Quang D.

Art Unit: 2811

**AMENDMENT TRANSMITTAL**

Commissioner for Patents  
Washington, D.C. 20231

Sir:

Transmitted herewith is an amendment in the above-identified application.

- ☐ Small Entity status under 37 C.F.R. § 1.9 and § 1.27 has been established by a Small Entity statement previously submitted.
- ☐ Small Entity statement is enclosed.
- ☒ The fee required for additional claims is calculated below:

	Claims as Amended		Previously Paid For		Extra Claims Present		Rate		Additional Claims Fee
Total Claims:	28	—	24	=	4	x	\$18.00	=	\$72.00
Independents:	4	—	4	=	0	x	\$84.00	=	\$0.00
First presentation of any Multiple Dependent Claims:						+	\$280.00	=	\$0.00
CLAIMS FEE TOTAL:									\$72.00

- ☒ A check in the amount of \$72.00 is enclosed.

- ☒ The Commissioner is hereby authorized to charge any additional fees which may be required regarding this application under 37 C.F.R. §§ 1.16-1.17, or credit any overpayment, to Deposit Account No. 19-0741. Should no proper payment be enclosed herewith, as by a check being in the wrong amount, unsigned, post-dated, otherwise improper or informal or even entirely missing, the Commissioner is authorized to charge the unpaid amount to Deposit Account No. 19-0741.

Please direct all correspondence to the undersigned attorney or agent at the address indicated below.

Respectfully submitted,

November 6, 2002  
Date

Phillip J. Articola  
Phillip J. Articola  
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#14/B  
11-15-02  
Jms.

AMENDMENT AND REPLY TO 37 C.F.R. §1.111

Commissioner for Patents  
Washington, D.C. 20231

Sir:

In reply to the Office Action dated August 14, 2002, please amend the application as follows:

IN THE CLAIMS:

In accordance with 37 C.F.R. § 1.121, please substitute for original claims 1, 6, 11 and 18, the following rewritten versions of the same claims, as amended. The changes are shown explicitly in the attached "Marked Up Version Showing Changes Made."

Also, please add new claims 25-32 as provided below.

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